Vishay 威世 FEP30JP-E3 PDF



深圳创唯电子有限公司

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Vishay General Semiconductor

Dual Common Cathode Ultrafast Rectifier



PRIMARY CHARACTERISTICS								
I _{F(AV)}	30 A							
V _{RRM}	50 V, 100 V, 150 V, 200 V, 300 V, 400 V, 500 V, 600 V							
I _{FSM}	300 A							
t _{rr}	35 ns, 50 ns							
V_F at $I_F = 15$ A	0.95 V, 1.3 V, 1.5 V							
T _J max.	150 °C							
Package	TO-3P (TO-247AD)							
Circuit configuration	Common cathode							

FEATURES

- Power pack
- Glass passivated pellet chip junction

· Ultrafast recovery time

- · Low switching losses, high efficiency
- · Low thermal resistance
- High forward surge capability
- Solder dip 260 °C, 40 s
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, inverters, freewheeling diodes, DC/DC converters, and other power switching application.

MECHANICAL DATA

Case: TO-3P (TO-247AD)

Molding compound meets UL 94 V-0 flammability rating

Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs max.

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)										
PARAMETER	SYMBOL	FEP 30AP	FEP 30BP	FEP 30CP	FEP 30DP	FEP 30FP	FEP 30GP	FEP 30HP	FEP 30JP	UNIT
Maximum repetitive peak reverse voltage	V_{RRM}	50	100	150	200	300	400	500	600	V
Maximum RMS voltage	V _{RMS}	35	70	105	140	210	280	350	420	V
Maximum DC blocking voltage	V_{DC}	50	100	150	200	300	400	500	600	V
Maximum average forward rectified current at T _C = 100 °C	I _{F(AV)}	30						Α		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I _{FSM}	300					Α			
Operating storage and temperature range	T_J , T_{STG}	-55 to +150						°C/W		



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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)											
PARAMETER	TEST CONDITIONS	SYMBOL	FEP 30AP	FEP 30BP	FEP 30CP	FEP 30DP	FEP 30FP	FEP 30GP	FEP 30HP	FEP 30JP	UNIT
Maximum instantaneous forward voltage per diode	15.0 A	V _F		0.95 1.3				.3	1.5		V
Maximum DC reverse current at	T _C = 25 °C		10								
rated DC blocking voltage per diode	T _C = 100 °C	I _R				50	500				μA
Maximum reverse recovery time per diode	$I_F = 0.5 A,$ $I_R = 1.0 A,$ $I_{rr} = 0.25 A$	t _{rr}	35 50					ns			
Typical junction capacitance per diode	4.0 V, 1 MHz	CJ	175 145					pF			

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)										
PARAMETER	SYMBOL	OL FEP FEP FEP FEP FEP FEP FEP SOME SOME								
Typical thermal resistance per diode	R ₀ JC (1)	1.0 °C/						°C/W		

Note

 $^{^{(1)}}$ Thermal resistance from junction to case per diode mounted on heatsink

ORDERING INFORMATION (Example)										
PACKAGE	ACKAGE PREFERRED P/N UNIT WEIGHT (g) PACKAGE CODE BASE QUANTITY DELIVERY MODE									
TO-247AD	FEP30JP-E3/45	6.15	30	30/tube	Tube					



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RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

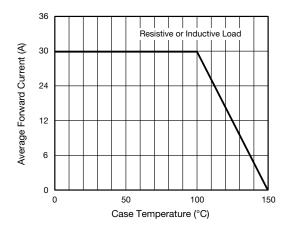


Fig. 1 - Forward Current Derating Curve

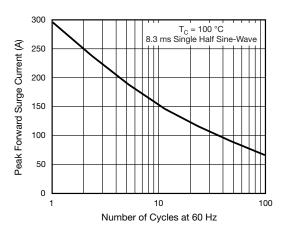


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

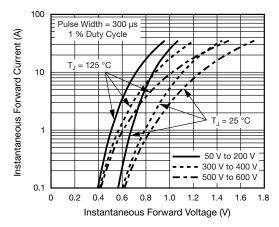


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

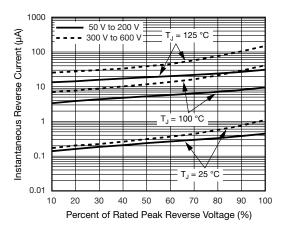


Fig. 4 - Typical Reverse Leakage Characteristics Per Diode

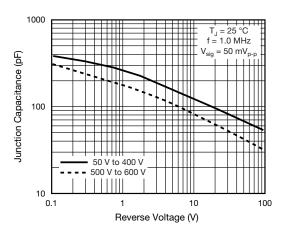


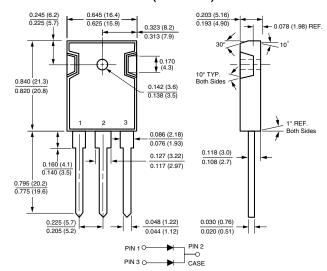
Fig. 5 - Typical Junction Capacitance Per Diode



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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

TO-3P (TO-247AD)





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